NSN 5961-01-499-8875

A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-499-8875 **Inclosure Material:** Plastic **Overall Length:** Between 0.110 inches and 0.120 inches **Overall Height:** Between 0.035 inches and 0.043 inches **Overall Width:** Between 0.047 inches and 0.055 inches **End Application:** C-17a aircraft **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 breakover voltage, instantaneous **Current Rating Per Characteristic:** 600.00 milliamperes source cutoff current preset **Capacitance Rating In Picofarads:** 4.0 **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Request name diode semiconductor device: use on 473597-4 smoke dectertor/model 2000: breakdown voltage with test conditions ir=50microamperes, min. 200volts **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: